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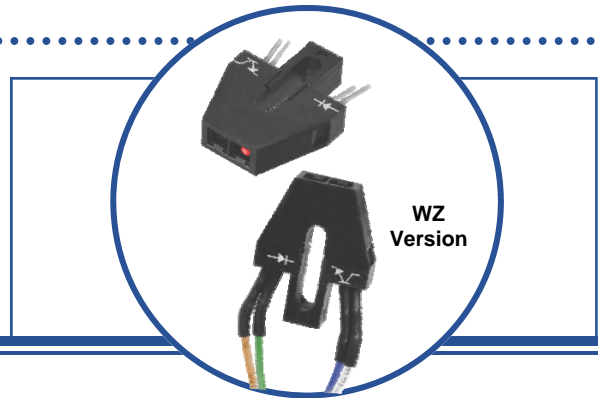
Jameco Part Number 1872741

**Reflective Object Sensor**  
**OPB703, OPB704, OPB705**  
**OPB703WZ, OPB704WZ, OPB705WZ, OPB70AWZ,**  
**OPB70BWZ, OPB70CWZ, OPB70DWZ**



**Features:**

- Phototransistor output
- High sensitivity
- Low-cost plastic housing
- Available with lenses for dust protection and ambient light filtration



**Description:**

The **OPB703, OPB704** and **OPB705** consist of an Infrared (890nm) Light Emitting Diode (LED) and a NPN silicon Phototransistor, mounted side-by-side on converging optical axes in a black plastic housing and are designed for PCBoard mounting. The **OPB703WZ, OPB704WZ, OPB705WZ** and **OPB70BWZ** are designed for remote mounting utilizing interconnect wires of UL approved 26 AWG, 24" (61.0cm) minimum length, stripped and tinned.

The **OPB70AWZ** consist of an Infrared (890nm) Light Emitting Diode (LED) and a NPN silicon Photodarlington, mounted side-by-side on converging optical axes in a black plastic housing and are designed for remote mounting utilizing interconnect wires of UL approved 26 AWG, 24" (61.0cm) minimum length, stripped and tinned.

The **OPB70CWZ** and **OPB70DWZ** consist of an Visible (Red 640nm) Light Emitting Diode (LED) and a NPN silicon Phototransistor or Rbe Phototransistor, mounted side-by-side on converging optical axes in a black plastic housing and are designed for remote mounting utilizing interconnect wires of UL approved 26 AWG, 24" (61.0cm) minimum length, stripped and tinned.

Various lens options are available: No lens for the (**OPB703, OPB703WZ**), blue window for dust protection for the (**OPB704, OPB704WZ, OPB70BWZ**) and Aperture lens for improved resolution for the (**OPB705, OPB705WZ, OPB70AWZ, OPB70CWZ** and **OPB70DWZ**).

The phototransistor responds to illumination from the emitter when a reflective object passes within the field of view centered typically at 0.15" (3.8 mm).

Custom electrical, wire, cabling and connectors are available. Contact your local representative or OPTEK for more information.

**Applications:**

- Non-contact reflective object sensor
- Assembly line automation
- Machine automation
- Machine safety
- End of travel sensor
- Door sensor

Ordering Information						
Part	LED Peak			Lead or Wire		
OPB703	890 nm	Transistor	None	0.160" Leads		
OPB703WZ				24" / 26 AWG Wire		
OPB704			Blue Window	0.160" Leads		
OPB704WZ				24" / 26 AWG Wire		
OPB705			Aperture	0.160" Leads		
OPB705WZ				24" / 26 AWG Wire		
OPB70AWZ					Darlington	
OPB70BWZ				Rbe Transistor		
OPB70CWZ			640 nm	Rbe Transistor	Aperture	24" / 26 AWG Wire
OPB70DWZ				Transistor		



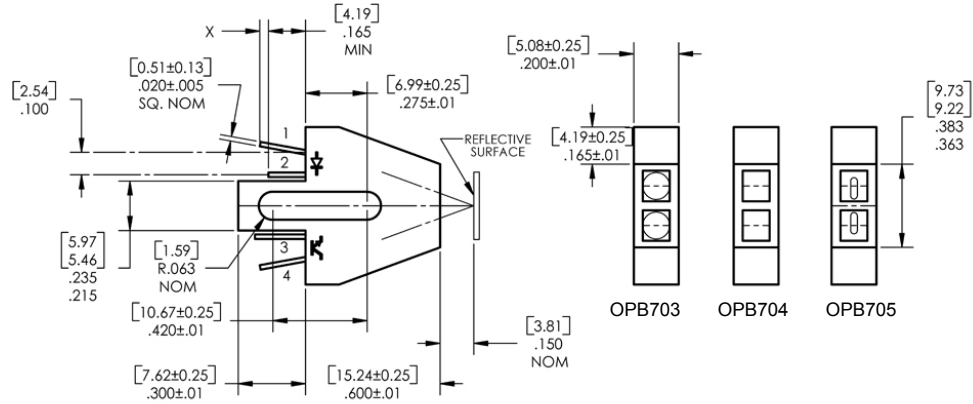
**RoHS**

OPTEK reserves the right to make changes at any time in order to improve design and to supply the best product possible.

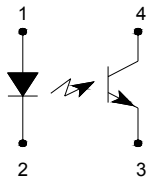
**Reflective Object Sensor**  
**OPB703, OPB704, OPB705**  
**OPB703WZ, OPB704WZ, OPB705WZ, OPB70AWZ,**  
**OPB70BWZ, OPB70CWZ, OPB70DWZ**



**OPB 703, OPB704, OPB705**



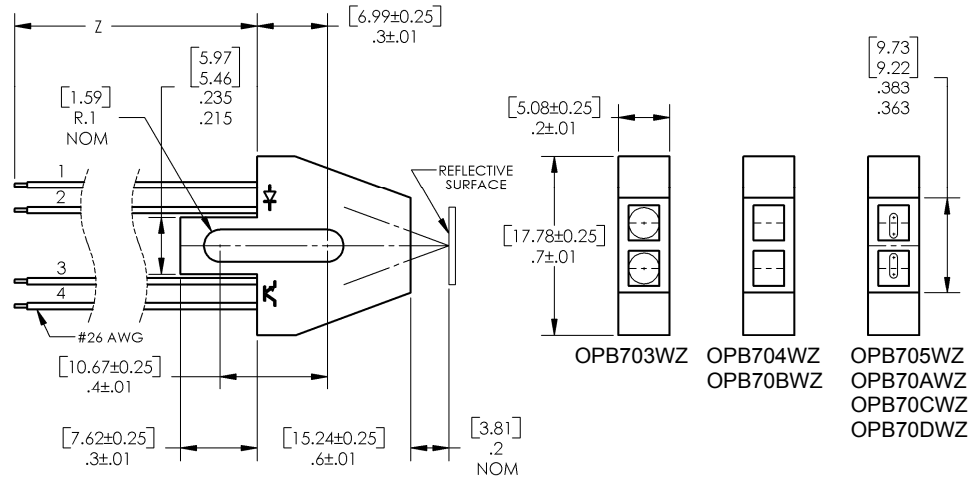
**OPB703, OPB704, OPB705**



Pin #	Description	Pin #	Description
1	Anode	4	Collector
2	Cathode	3	Emitter

**OPB 703WZ, OPB704WZ, OPB705WZ, OPB70AWZ, OPB70BWZ, OPB70CWZ, OPB70DWZ**

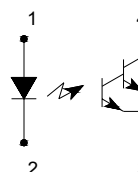
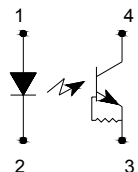
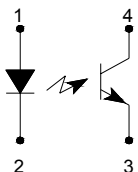
Pin - Color	LED
1 – Orange	Anode
2 – Green	Cathode
3 – Blue	Emitter
4 – White	Collector



**OPB703WZ, OPB704WZ, OPB705WZ, OPB70DWZ**

**OPB703BZ, OPB704CZ**

**OPB703AWZ**



DIMENSIONS ARE IN: [ MILLIMETERS]  
INCHES

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**OPB70BWZ, OPB70CWZ, OPB70DWZ**



**Absolute Maximum Ratings** ( $T_A=25^\circ\text{C}$  unless otherwise noted)

Storage Temperature Range	-40°C to +85° C
Lead Soldering Temperature [1/16 inch (1.6 mm) from the case for 5 sec. with soldering iron]	240° C <sup>(1)</sup>

**Input Diode**

Forward DC Current	40 mA
Reverse DC Voltage	2 V
Power Dissipation	100 mW <sup>(2)</sup>

**Output Phototransistor**

Collector-Emitter Voltage	30 V
Emitter-Collector Voltage	5 V
Collector DC Current	25 mA
Power Dissipation	100 mW <sup>(2)</sup>

**Electrical Characteristics** ( $T_A = 25^\circ\text{C}$  unless otherwise noted)

**(OPB703, OPB703WZ, OPB704, OPB704WZ, OPB705, OPB705WZ, OPB70BWZ)**

SYMBOL	PARAMETER	MIN	TYP	MAX	UNITS	TEST CONDITIONS
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**Input Diode** (See OP265 for additional information — for reference only)

$V_F$	Forward Voltage	0.9	-	1.7	V	$I_F = 40\text{mA}$
$I_R$	Reverse Current	-	-	100	$\mu\text{A}$	$V_R = 2\text{V}$

**Output Phototransistor** (See OP505 for additional information — for reference only)

$V_{(BR)CEO}$	Collector-Emitter Breakdown Voltage	30	-	-	V	$I_{CE} = 100\ \mu\text{A}$
$V_{(BR)ECO}$	Emitter-Collector Breakdown Voltage	5	-	-	V	$I_{EC} = 100\ \mu\text{A}$
$I_{CEO}$	Collector Dark Current	-	-	250	nA	$V_{CE} = 10\text{V}, I_F = 0, E_E = 0$

**Coupled**

$I_{C(ON)}$	On-State Collector Current					
	OPB703, OPB703WZ	0.30	-	2.5	mA	$V_{CE} = 5\text{V}, I_F = 40\text{mA}, d = 0.15''^{(3)(7)}$
	OPB704, OPB704WZ	0.20	-	2.5		
OPB705, OPB705WZ, OPB70BWZ	0.15	-	1.0			
$I_{CX}$	Crosstalk				$\mu\text{A}$	$V_{CE} = 5\text{V}, I_F = 40\text{mA}^{(6)}$
	OPB703, OPB703WZ	-	-	20		
	OPB704, OPB704WZ	-	-	20		
	OPB705, OPB705WZ, OPB90BWZ	-	-	10		

Notes:

- (1) RMA flux is recommended. Duration can be extended to 10 seconds maximum when flow soldering.
- (2) For OPB703, OPB704 and OPB705, derate linearly 1.67 mW/° C above 25° C.
- (3) For OPB703WZ, OPB704WZ, OPB705WZ and OPB70BWZ, derate linearly 1.82 mW/° C above 25° C.
- (4) The distance from the assembly face to the reflective surface is d.
- (5) Lower curve is based on a calculated worst-case condition, rather than the conventional -2 $\Omega$  limit.
- (6) Crosstalk ( $I_{CX}$ ) is the collector current measured with the indicated current in the input diode and with no reflecting surface.
- (7) Measured using Eastman Kodak neutral white test card with 90% diffuse reflectance as a reflecting surface. Reference: Eastman Kodak, Catalog # E 152 7795.
- (8) All parameters tested using pulse techniques.

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**Reflective Object Sensor**  
**OPB703, OPB704, OPB705**  
**OPB703WZ, OPB704WZ, OPB705WZ, OPB70AWZ,**  
**OPB70BWZ, OPB70CWZ, OPB70DWZ**



**Electrical Characteristics** ( $T_A = 25^\circ\text{C}$  unless otherwise noted)  
**(OPB70AWZ)**

SYMBOL	PARAMETER	MIN	TYP	MAX	UNITS	TEST CONDITIONS
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**Input Diode** (See OP265 for additional information — for reference only)

$V_F$	Forward Voltage	0.9	-	1.7	V	$I_F = 40\text{mA}$
$I_R$	Reverse Current	-	-	100	$\mu\text{A}$	$V_R = 2\text{V}$

**Output PhotoDarlington** (See OP535 for additional information — for reference only)

$V_{(BR)CEO}$	Collector-Emitter Breakdown Voltage	15	-	-	V	$I_{CE} = 1.0\text{mA}, E_E = 0$
$V_{(BR)ECO}$	Emitter-Collector Breakdown Voltage	5	-	-	V	$I_{EC} = 100\mu\text{A}, E_E = 0$
$I_{CEO}$	Collector Dark Current	-	-	250	nA	$V_{CE} = 10\text{V}, I_F = 0, E_E = 0$

**Coupled**

$I_{C(ON)}$	On-State Collector Current	5.0	-	26.0	mA	$V_{CE} = 5\text{V}, I_F = 40\text{mA}, d = 0.15''^{(2)(6)}$
$V_{(SAT)}$	Saturation Voltage	0.60	-	1.15	V	$I_{C(ON)} = 400\mu\text{A}, I_F = 40\text{mA}, d = 0.15''^{(2)(6)}$
$I_{CX}$	Crosstalk	-	-	25	$\mu\text{A}$	$V_{CE} = 5\text{V}, I_F = 40\text{mA}^{(5)}$

Notes:

- (1) RMA flux is recommended. Duration can be extended to 10 seconds maximum when flow soldering.
- (2) Derate linearly  $1.82\text{mW}/^\circ\text{C}$  above  $25^\circ\text{C}$ .
- (3) The distance from the assembly face to the reflective surface is  $d$ .
- (4) Lower curve is based on a calculated worst-case condition, rather than the conventional  $-2\Omega$  limit.
- (5) Crosstalk ( $I_{CX}$ ) is the collector current measured with the indicated current in the input diode and with no reflecting surface.
- (6) Measured using Eastman Kodak neutral white test card with 90% diffuse reflectance as a reflecting surface. Reference: Eastman Kodak, Catalog # E 152 7795.
- (7) All parameters tested using pulse techniques.

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**Reflective Object Sensor**  
**OPB703, OPB704, OPB705**  
**OPB703WZ, OPB704WZ, OPB705WZ, OPB70AWZ,**  
**OPB70BWZ, OPB70CWZ, OPB70DWZ**



**Electrical Characteristics** ( $T_A = 25^\circ\text{C}$  unless otherwise noted)  
**(OPB70CWZ and OPB70DWZ)**

SYMBOL	PARAMETER	MIN	TYP	MAX	UNITS	TEST CONDITIONS
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**Input Diode** (See OVLAS6CB8 for additional information — for reference only)

$V_F$	Forward Voltage	1.6	-	2.5	V	$I_F = 40\text{mA}$
$I_R$	Reverse Current	-	-	100	$\mu\text{A}$	$V_R = 2\text{V}$

**Output Phototransistor** (See OP505 for additional information — for reference only)

$V_{(BR)CEO}$	Collector-Emitter Breakdown Voltage	30	-	-	V	$I_{CE} = 100\ \mu\text{A}, I_F = 0, E_E = 0$
$V_{(BR)ECO}$	Emitter-Collector Breakdown Voltage	0.4	-	-	V	$I_{EC} = 100\ \mu\text{A}, I_F = 0, E_E = 0$
$I_{CEO}$	Collector Dark Current	-	-	250	nA	$V_{CE} = 10\text{V}, I_F = 0, E_E = 0$

**Coupled**

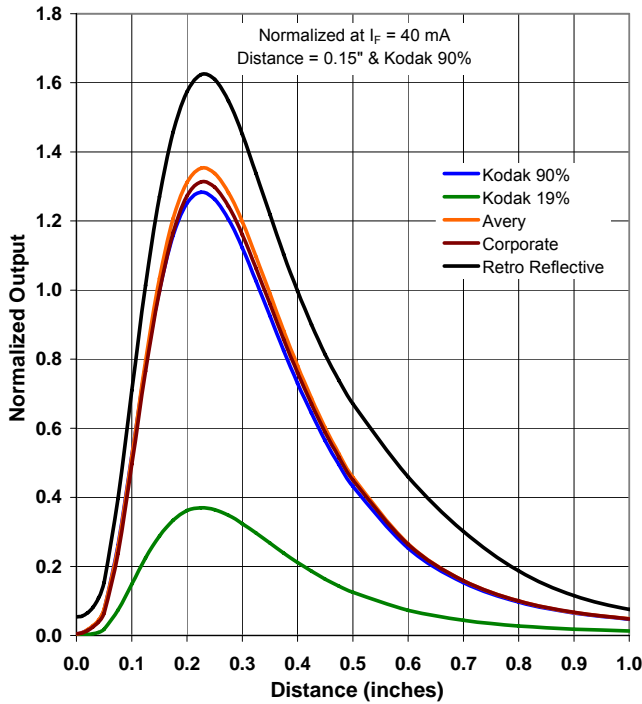
$I_{C(ON)}$	On-State Collector Current OPB70CWZ, OPB70DWZ	0.10	-	1.0	mA	$V_{CE} = 5\text{V}, I_F = 40\text{mA}, d = 0.15''^{(2)(6)}$
$V_{(SAT)}$	Saturation Voltage	-	-	0.4	V	$I_{C(ON)} = 400\ \mu\text{A}, I_F = 40\text{mA}, d = 0.15''^{(2)(6)}$
$I_{CX}$	Crosstalk OPB70CWZ, OPB70DWZ	-	-	0.1	$\mu\text{A}$	$V_{CE} = 5\text{V}, I_F = 40\text{mA}^{(5)}$

Notes:

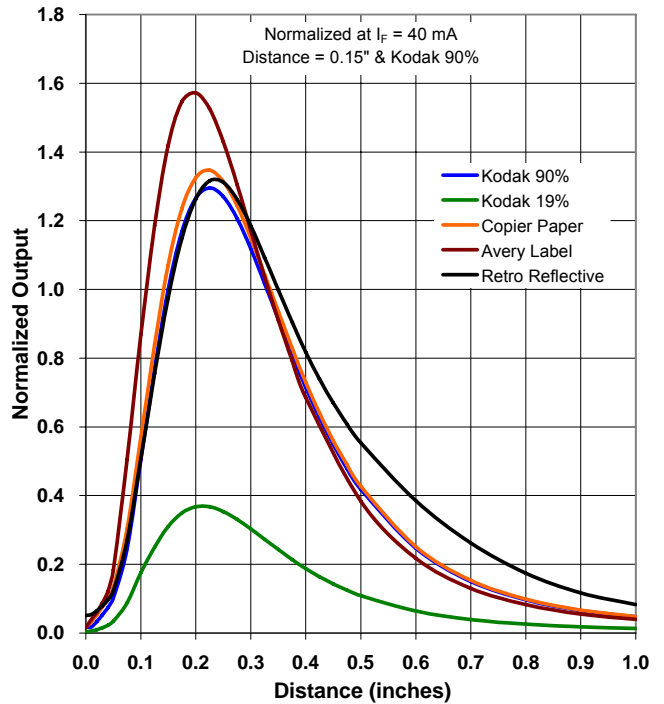
- (1) RMA flux is recommended. Duration can be extended to 10 seconds maximum when flow soldering.
- (2) For OPB703WZ, OPB704WZ, OPB705WZ and OPB70BWZ, derate linearly  $1.82\text{ mW}/^\circ\text{C}$  above  $25^\circ\text{C}$ .
- (3) The distance from the assembly face to the reflective surface is  $d$ .
- (4) Lower curve is based on a calculated worst-case condition, rather than the conventional  $-2\Omega$  limit.
- (5) Crosstalk ( $I_{CX}$ ) is the collector current measured with the indicated current in the input diode and with no reflecting surface.
- (6) Measured using Eastman Kodak neutral white test card with 90% diffuse reflectance as a reflecting surface. Reference: Eastman Kodak, Catalog # E 152 7795.
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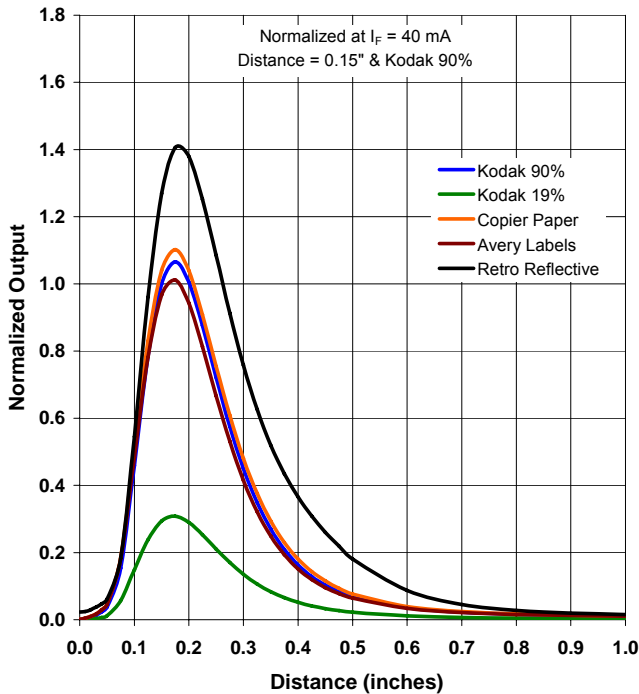
**OPB703—Output Distance**



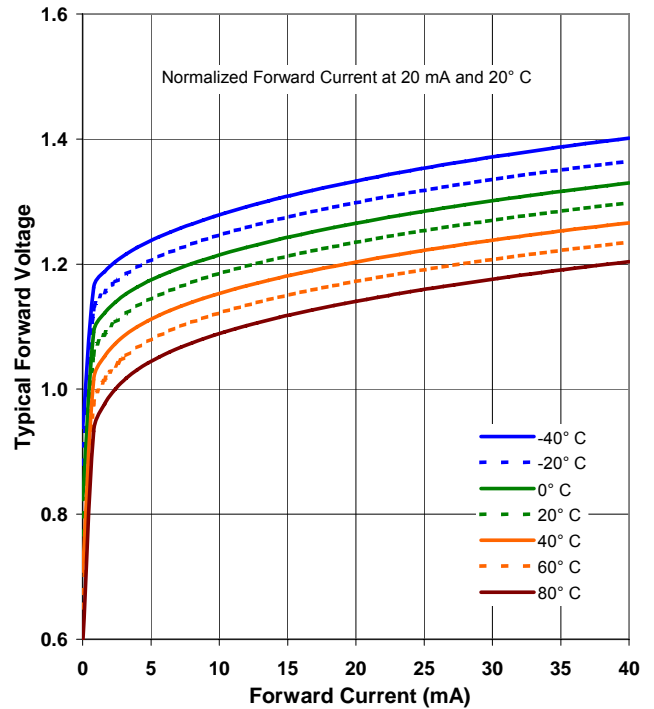
**OPB704, OPB70B—Output Distance**



**OPB705, OPB70A, OPB70C, OPB70D—Output Distance**



**Forward Voltage vs Forward Current vs Temp**



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